



MBR0520G THRU MBR0504G

Low VF Chip Schottky Barrier Rectifier

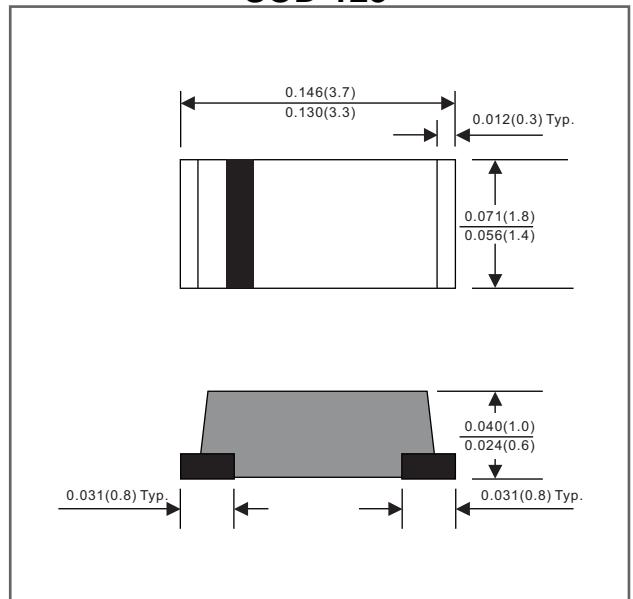
0.5A Surface Mount Schottky Barrier Rectifiers - 20V- 40V

Package outline

SOD-123

Features

- Batch process design, excellent power dissipation offers better reverse leakage current and thermal resistance.
- Low profile surface mounted application in order to optimize board space.
- Tiny plastic SMD package.
- Low power loss, high efficiency.
- High current capability, low forward voltage drop.
- High surge capability.
- Guardring for overvoltage protection.
- Ultra high-speed switching.
- Silicon epitaxial planar chip, metal silicon junction.
- Lead-free parts meet environmental standards of MIL-STD-19500/228
- Suffix "-H" indicates Halogen free parts, ex. MBR0520G-H.



Dimensions in inches and (millimeters)

Mechanical data

- Epoxy: UL94-V0 rated frame retardant
- Case: Molded plastic, SOD-123
- Terminals: Solder plated, solderable per MIL-STD-750, Method 2026
- Polarity: Indicated by cathode band
- Mounting Position: Any
- Weight: Approximated 0.011 gram

Maximum ratings (AT $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	CONDITIONS	Symbol	MIN.	TYP.	MAX.	UNIT
Forward rectified current	See Fig.2	I_o			0.5	A
Forward surge current	8.3ms single half sine-wave superimposed on rate load (JEDEC methode)	I_{FSM}			15	A
Reverse current	$V_R = V_{RRM} T_J = 25^\circ\text{C}$	I_R			1.0	mA
Thermal resistance	Junction to ambient	R_{BJA}		42		$^\circ\text{C}/\text{W}$
Diode junction capacitance	f=1MHz and applied 4V DC reverse voltage	C_J		130		pF
Storage temperature		T_{STG}	-65		+175	$^\circ\text{C}$

SYMBOLS	V_{RRM} *1 (V)	V_{RMS} *2 (V)	V_R *3 (V)	V_F *4 (V)	Operating temperature T_J , ($^\circ\text{C}$)
MBR0520G	20	14	20	0.38	-55 to +100
MBR0530G	30	21	30	0.40	
MBR0540G	40	28	40	0.40	

*1 Repetitive peak reverse voltage

*2 RMS voltage

*3 Continuous reverse voltage

*4 Maximum forward voltage@ $I_F=0.5\text{A}$

Rating and characteristic curves

FIG.1-TYPICAL FORWARD CHARACTERISTICS

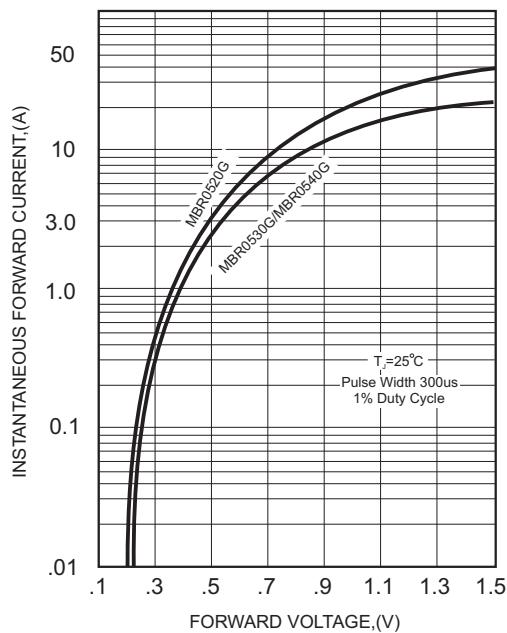


FIG.3 - TYPICAL REVERSE CHARACTERISTICS

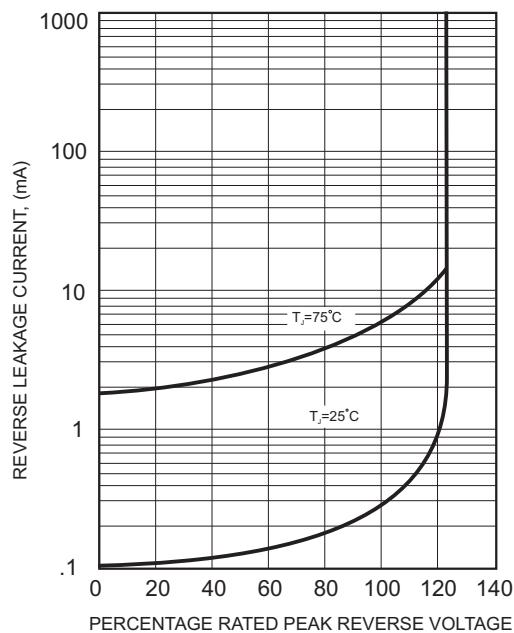


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

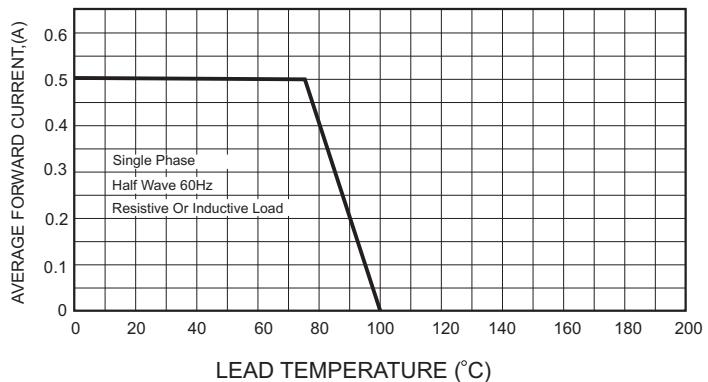


FIG.4-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

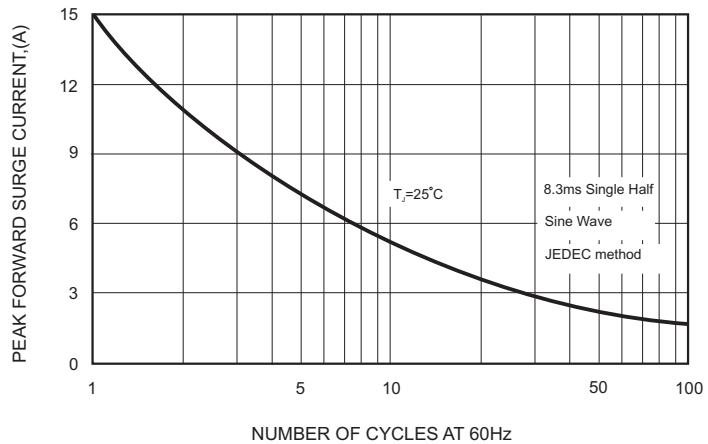


FIG.5-TYPICAL JUNCTION CAPACITANCE

